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PATENT APPLICATION

EFFICIENT LOW DROPOUT LINEAR REGULATOR

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CROSS-REFERENCE TO RELATED APPLICATION

[01] The present invention is related to co-pending U.S. Application __/__, filed
5 February 27, 2004 (atty. docket no. 16869Q-092300US), and is herein incorporated by
reference in its entirety for all purposes.

BACKGROUND OF THE INVENTION

[02] The present invention relates generally to analog circuits, and in particular low
10 dropout linear regulators and systems which incorporate low dropout linear regulators.

[03] Most linear regulators have feedback which needs some type of stability
compensation, either external or internal compensation. To obtain more precise voltage
regulation, larger gain is required which inherently makes the feedback less stable. These
two trade-offs, large gain and stability, create a design challenge. Other design

15 considerations require low current, reduced silicon area, and good power supply rejection.
Many techniques have been implemented for stability compensation. The following patents
constitute a sampling of conventional solutions: U.S. Pat. Nos. 4,908,566, 5,168,209,
5,637,992, 5,648,718, 5,744,944, 5,850,139, 5,945,818, 5,982,226, and 6,522,112. All of
these techniques use some type of internal zero compensation.

20 [04] Fig. 3 shows a simplified open loop transfer function of a linear regulator. A
regulator with feedback becomes unstable if the open loop gain is > 0 dB and the phase is
-180 degrees. This condition occurs if at least 2 poles exist below the unity gain bandwidth
(UGB). The zero compensation method from the cited patents essentially adds 90 degrees
back to the transfer function and keeps the loop stable. Methods to add zero compensation
25 typically increase the power requirement of the circuit and increase the silicon area,
especially if large capacitors are needed in silicon.

[05] The P_0 pole in Fig. 3 is typically caused by a main compensating load capacitor C_1 , as
shown in Fig. 4. P_a of Fig. 3 represents a secondary pole that can be caused by parasitic
capacitive loading (C_{p1}) at the gate of T_1 or by a parasitic capacitance (C_{p2}) at the base of
30 T_{pass} , or even by the OpAmp itself. In general, a circuit arrangement can cause stability
problems if at least 2 poles exist below the UGB (i.e., less than the unity gain frequency) and
no zero compensation is provided.

[06] In essence there are many places where secondary poles can exist. As in Fig. 4, nodes V_1 , V_3 , V_f , V_{out} and the OpAmp are potential areas where poles exist. Node V_3 , however, can be the most difficult node to keep sufficiently low in parasitic capacitance, since it has to drive off the chip and at the base of the Pass transistor resulting in 10's of pF's.

5 [07] The other traditional method of stability compensation is to rely on the ESR (equivalent series resistance) of the load capacitor. The ESR of the load capacitor can provide a compensating zero to offset the extra pole in the feedback typically from the amplifier stage. The issue with relying on the ESR of the capacitor is there can be a narrow range of ESR values allowed for a given design.

10 [08] There is need for an integrated linear regulator have relatively large gain while maintaining stability, with reduced chip layout area and reduced power consumption.

SUMMARY OF THE INVENTION

[09] The present invention is directed to a linear regulator and circuits incorporating a
15 linear regulator. A typical linear circuit according to the invention includes an external pass transistor that does not rely on internal compensation, provides high gain, and exhibits reduced silicon area and power requirements. Circuits according to the present invention provide sufficient bandwidth with an error amplifier and drive capability to keep any secondary poles sufficiently far from the unity gain bandwidth (UGB) while maintaining
20 good power supply rejection. In accordance with the invention operation of the circuit does not rely on the equivalent series resistance (ESR) of the load capacitor.

BRIEF DESCRIPTION OF THE DRAWINGS

[10] Aspects, advantages and novel features of the present invention will become apparent
25 from the following description of the invention presented in conjunction with the accompanying drawings, wherein:

Fig. 1 shows an illustrative embodiment of a linear regulator circuit according to the present invention;

Fig. 2 shows a Bode plot of the behavior of the linear regulator circuit of Fig.
30 1;

Fig. 3 shows a Bode plot of a conventional linear regulator circuit;

Fig. 4 shows a typical linear regulator circuit;

Fig. 5A shows a disk drive system which incorporates a linear voltage regulator according to the invention; and

Fig. 5B shows another disk drive system which incorporates a linear voltage regulator according to the invention; and

Fig. 6 shows an example of a configuration using multiple OpAmps.

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DESCRIPTION OF THE SPECIFIC EMBODIMENTS

[11] Circuits embodied in accordance with the present invention keep the secondary poles beyond the UGB. See Fig. 2 for example. P_b represents a secondary pole in the system. As long as the secondary poles are sufficiently beyond the UGB (i.e., greater than the unity gain frequency), the regulator will be stable. There are many places where secondary poles can
10 exist. As can be seen in Fig. 4, for example, nodes V_1 , V_3 , V_f , V_{out} and the OpAmp are potential areas where poles exist. Node V_3 , however, can be an especially difficult node to keep sufficiently low in parasitic capacitance, since it has to drive off the chip and at the base of the pass transistor T_{pass} , resulting in capacitance of tens of pF's.

[12] Referring to Fig. 1, a linear regulator 100 includes an error amplifier comprising an
15 OpAmp circuit. In one embodiment, a single conventional OpAmp device is used. The OpAmp includes a non-inverting input that is coupled to a node which receives a reference voltage, V_{ref} . The OpAmp includes an inverting input that is coupled to a node V_f . An output of the OpAmp is coupled to a node V_1 . A current mirror circuit comprising transistors T_4 and T_1 is coupled to the node V_1 . The OpAmp outputs by way of the node V_1 a driving current to
20 the current mirror circuit. A voltage source $VDD2$ is provided to power the OpAmp. It can be appreciated by those of ordinary skill that alternative embodiments of the invention can incorporate an OpAmp circuit design configured around an arrangement of multiple OpAmp devices. Fig. 6 shows an example of a configuration in which the OpAmp component shown in Fig. 1 comprises multiple OpAmp devices.

[13] A resistor R_1 is coupled between a second voltage source $VDD1$ and the drain of T_1 at a node V_2 . Transistor device T_2 is configured as a source follower, having a gate terminal that is connected to the node V_2 and a source terminal that is connected to a current source represented schematically as I_s . The source terminal of T_2 is also coupled to I_b flowing at a node V_3 . Typical devices used for transistor device T_2 include, but are not limited to, P-type
25 FET's (field effect transistors), N-type FET's, NPN BJT's (bipolar junction transistors), and
30 PNP BJT's.

[14] A pass circuit comprising element T_{pass} has a control terminal that is connected to the node V_3 . The voltage source $VDD1$ is connected to a first terminal of the pass element T_{pass} . The pass element can be any of a number of transistor devices such as a BJT. Though, the

embodiment illustrated in Fig. 1 shows the device to be a device that is external to the linear regulator 100, one of ordinary skill will understand that the pass element can be incorporated on-chip.

[15] A second terminal of the pass element T_{pass} is coupled to an output node V_{out} to provide a regulated voltage to a load. A compensating capacitor C_1 is coupled across the load. An equivalent series inductance (ESL) of the capacitor is schematically represented. A feedback path from the output node V_{out} to the node V_f is provided through the voltage divider network formed by a pair of resistors R_f .

[16] In operation, a circuit according to the invention operates to drive the base node V_3 such that the bandwidth at that node is high enough to place a pole beyond the UGB. This ensures stability of the circuit while providing efficient operation for low quiescent current and good power supply rejection. Referring to the illustrative circuit according to the invention, shown in Fig. 1, the output of the OpAmp component is a current which drives the diode-connected mirror of T_4 and T_1 . Transistor device T_1 , with R_1 connected to its drain node, provides gain and a DC operating point at node V_2 .

[17] As noted above, the transistor device T_2 is configured as a source follower and thus operates as a low output impedance gain stage to provide a low impedance drive to node V_3 . Current source I_s provides a bias current to T_2 that is substantially less than the base current, I_b . The voltage source V_{DD1} provides a current to the pass transistor T_{pass} and a common voltage reference to R_1 . It is noted that the voltage source V_{DD2} does not have to be the same potential as V_{DD1} . However, in a particular embodiment of the invention V_{DD2} can be the same potential as V_{DD1} .

[18] The compensating capacitor C_1 provides the pole P_0 (see Fig. 2). Because T_2 is configured as a source follower, its output impedance is low. Consequently, the source follower output can drive the parasitic capacitance C_p of the pass element T_{pass} that exists on node V_3 to provide sufficient bandwidth so that the secondary pole P_b can be located beyond the frequency of the UGB. This effect is shown in Fig. 2, where the second pole is . The current for T_2 is provided primarily by the base of the pass element T_{pass} . This configuration exhibits certain advantages. For example, since the current required to supply base current to T_{pass} is low during low load current, the quiescent current for the total regulator is low.

[19] Another advantage with this configuration is that the source follower acts as a gain stage with an output impedance that decreases with an increase in load current. The current flow through transistor device T_2 increases as the current draw through the load increases. This in turn decreases the output resistance of T_2 thus increasing the bandwidth of node V_3 .

More bandwidth at V_3 is needed during higher current loads because the pole at V_{out} increases as well with higher current loads. So the poles at V_3 and V_{out} track each other despite the load change. This is a desirable characteristic because it ensures stability during high current loads.

5 [20] I_s is a small current to keep transistor device T_2 turned ON when no base current is needed during low current demands of the load. The current I_s serves as a replacement current when I_b becomes very small during a low loading conditions, to ensure a bias current through the source follower while allowing the pass element T_{pass} to shut off. This aspect of the invention ensures low quiescent power consumption.

10 [21] R_1 is used to set a normal bias point for node V_2 in the linear operating range of T_{pass} and to keep the pole at a frequency sufficiently higher than the UGB to ensure stable operation. The resistor R_1 is also used to keep the power supply rejection of the linear regulator low. If $VDD1$ changes, node V_2 will track this movement and force V_3 to move in the same manner to keep the base-emitter voltage of T_{pass} constant. As noted above, $VDD2$ and $VDD1$ could be the same potential, but can be different if the voltage $VDD2$ for the
15 OpAmp needs to be larger or smaller than $VDD1$.

[22] A key aspect of the invention, as embodied in the illustrative circuit of Fig. 3, is to keep the resulting bandwidth from the combined effect of the nodes V_f , V_1 , V_2 , V_3 and the OpAmp approximately a factor of 10 higher than the UGB to maintain stability. With the
20 illustrative circuit shown, keeping the bandwidths at these levels is reasonably achievable. Also, circuits according to the invention do not require a large amount of silicon area to implement and do not draw a large amount of current during operation. In fact, the OpAmp could be a series of OpAmps with several additional internal nodes, provided that the bandwidth of the nodes are sufficiently high.

25 [23] As a final observation, consideration with any linear regulator of the equivalent series inductance (ESL) needs to be understood. The resonance of the capacitor C_1 is determined by the capacitance and ESL. The resonance of the capacitor should be chosen to be higher than the UGB.

[24] Generally, a linear voltage regulator circuit according to the present invention, can be
30 used in many electronic circuits which require a regulated voltage. Fig. 5A shows an example of the present invention as embodied in an electronic device. In particular, a hard disk drive system 500 is shown. Typical components include a magnetic head component 522 for reading tracks of data from a disk 512. A signal representing the modulated light signal is sensed by a pre-amp circuit 524 and delivered to a data channel 526. Main power

from a computer (not shown) supplies power to the whole drive. However, the voltage requirements for the pre-amp circuit 524, the data channel 526, a controller 528, and a motor and actuator circuit 530, each have different supply level requirements, current draw, tolerance and voltage ripple requirements. Imbedded in the data channel 526 and the controller 528 typically are sensitive circuits such as phase-locked loops and signal processing circuitry which require tighter tolerance and less “noisy” supplies than the motor and actuator circuit 530, for example. In Fig. 5A, Vcc supplies power to a PNP transistor pass element 504, and may be provided by a switching power supply and will have a higher tolerance and ripple.

[25] A linear regulator circuit 502 in accordance with the present invention is provided to control the pass element 504. The voltage nodes of 502 correspond to the same nodes as Fig. 1. The linear regulator circuit 502 of the present invention will supply a tighter tolerance and quieter supply to these sensitive circuits in the data channel and controller. The V_{out} shown in Fig. 5A is the linear regulator output and supplies power to circuits 526 and 528 at Vdd. The voltage supply Vcc shown in Fig. 5A couples to the VDD1 supply of Fig. 1.

[26] Providing VDD2 separate from VDD1 allows a lower voltage to be used for the pass element than for the opamp. For example, VDD2 = 3.3V is a typical power supply voltage for an opamp. However, typical HDD electronics can be driven at a lower voltage of 2.5 V. Thus, setting VDD1 to 2.5 V provides about a 0.8V drop in HDD supply voltage levels with corresponding drops in power loss and heat dissipation.

[27] Fig. 5B illustrates another configuration of a hard disk drive system 500'. Here, the linear regulator circuit 502 is shown incorporated in the controller component 528.